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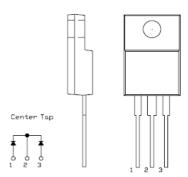
MBRF20150CTL SCHOTTKY RECTIFIER

Applications:

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

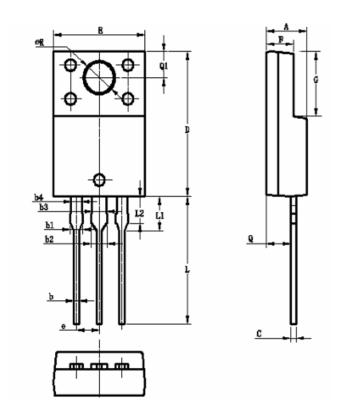
Features:

- 150 °C T_J operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request



OUTLINE DRAWING

Mechanical Dimensions: In mm



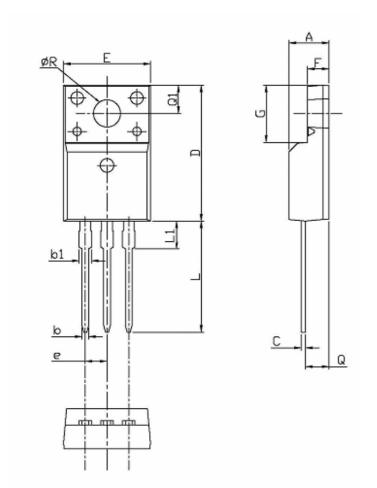
	OPTION 1(CJ)		OPTIO	N 2(HD)
Dim	Min	Max	Min	Max
Α	4.4	4.6	4.30	4.70
b	0.6T	ΥP	0.50	0.75
b1	1.3T	ΥP	1.30	1.40
b2	1.7T	ΥP	1.70	1.80
b3	1.6T	ΥP	1.50	1.75
b4	1.2T	ΥP	1.10	1.35
С	0.60	ГҮР	0.50	0.75
D	14.8	15.1	14.80	15.20
Е	10.06	10.26	9.96	10.36
е	2.55TYP		2.54TYP	
F	2.9	3.1	2.80	3.20
G	6.5	6.9	6.50	6.90
L	12.7	13.7	13.2	12.8
L1	3.4	3.8	3.60	4.00
L2	2.6	3.0	-	-
Q	2.5	2.9	2.50	2.90
Q1	2.5	2.9	2.70REF	
ØR	3.5REF		3.50REF	

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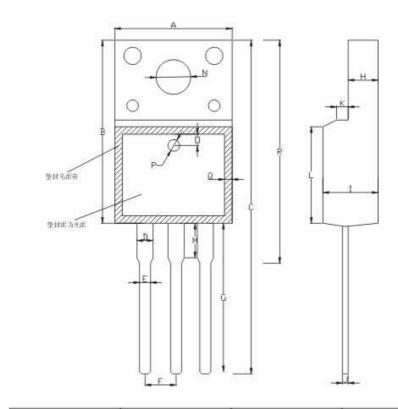


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	OPTION 3		OPTION 4		
Dim	Min	Max	Min	Max	
Α	4.53	4.93	4.50	4.90	
b	0.71	0.91	0.70	0.90	
b1	1.15	1.39	1.33	1.47	
С	0.36	0.53	0.45	0.60	
D	15.67	16.07	15.67	16.07	
Е	9.96	10.36	9.96	10.36	
е	2.547	ГҮР	2.54 BSC		
F	2.34	2.76	2.34	2.74	
G	6.50	6.90	6.48	6.88	
L	12.37	12.77	12.78	13.18	
L1	2.23	2.63	3.03	3.43	
Q	2.56	2.96	2.56	2.96	
Q1	3.10	3.50	3.10	3.50	
ØR	2.98	3.38	3.08	3.28	

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A:10.20	± 0.50	B:15.90	±0.50	C:29.00	± 1.00	D:1.24	± 0.10
E:0.80	± 0.10	F:2.54	± 0.10	G:13.10	$\pm 1,0$	H:2.55	± 0.05
I:4.70	±0.05	J:0.50	± 0.05	K:1.20	± 0.20	L:8.00	±0.50
M:3.00	± 0.50	N:3.20	± 0.20	O:1,25	± 0.05	P:1.5	±0.05
Q:1.0	±0.20	R:19.2	±1.0				

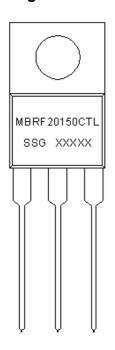
OPTION 5(SR)

ITO-220AB



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Marking Diagram:



Where XXXXX is YYWWL

MBR = Device Type F = Package type

20 = Forward Current (20A) 150 = Reverse Voltage (150V)

CTL = Configuration

 SSG
 = SSG

 YY
 = Year

 WW
 = Week

 L
 = Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

Ordering Information:

Device	Package	Shipping
MBRF20150CTL	ITO-220AB	50pcs / tube
	(Pb-Free)	•

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V_{RWM}	-	150	V
Max. Average Forward	I _{F(AV)}	50% duty cycle @T _C =133℃, rectangular wave form	20	А
Max. Peak One Cycle Non- Repetitive Surge Current (per leg)	I _{FSM}	8.3 ms, half Sine pulse	220	А

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Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop	V_{F1}	@ 10A, Pulse, T _J = 25 °C	0.95	V
(per leg)*	V_{F2}	@ 10 A, Pulse, T _J = 125 °C	0.80	V
Max. Reverse Current at DC	I _{R1}	$@V_R = rated V_R$	1.0	mA
condition (per leg)		T _J = 25 °C		
Max. Reverse Current (per	I _{R2}	$@V_R = rated V_R$	6.0	mA
leg)*		T _J = 125 °C		
Non-Repetitive Avalanche	Eas	T _J = 25 °C, I _{AS} = 2 A,	2	mJ
Energy		L = 1mH		
Max. Junction Capacitance	C _T	$@V_R = 5V, T_C = 25 ^{\circ}C$	400	pF
(per leg)		$f_{SIG} = 1MHz$		
Typical Series Inductance	L _S	Measured lead to lead 5 mm from	8.0	nH
(per leg)		package body		
Max. Voltage Rate of Change	dv/dt	-	10,000	V/μs
RSM Isolation Voltage	V_{ISO}	Clip mounting, the epoxy body	4500	V
(t = 1.0 second, R. H. < =30%,		away from the heatsink edge by		
$T_A = 25 ^{\circ}C$		more than 0.110" along the lead		
		direction.		
		Clip mounting, the epoxy body is	3500	
		inside the heatsink.		
		Screw mounting, the epoxy body	1500	
		is inside the heatsink.		

^{*} Pulse Width < 300µs, Duty Cycle <2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units _
Max. Junction Temperature	T_J	-	-55 to +150	°C
Max. Storage Temperature	T _{stg}	-	-55 to +150	°C
Maximum Thermal Resistance Junction to Case (per leg)	R _{θJC}	DC operation	3.5	°C/W
Approximate Weight	wt	-	2	g
Case Style		ITO-220AB		

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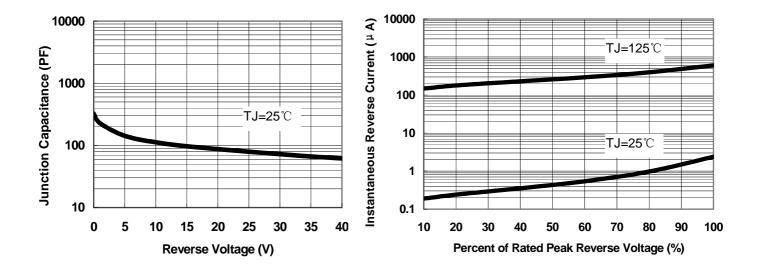


Fig.1-Typical Junction Capacitance

Fig.2-Typical Reverse Characteristics

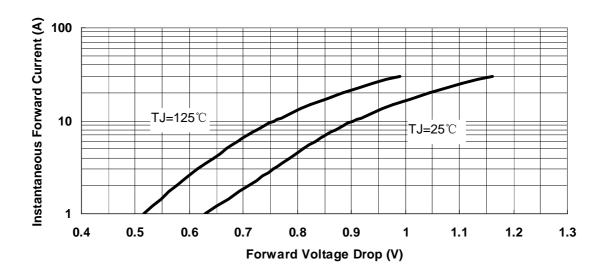


Fig.3-Typical Instantaneous Forward Voltage Characteristics

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MBRF20150CTL

Technical Data
Data Sheet N0150 Rev. A

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